

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

# 2SC5612

HORIZONTAL DEFLECTION OUTPUT FOR COLOR TV

Unit: mm

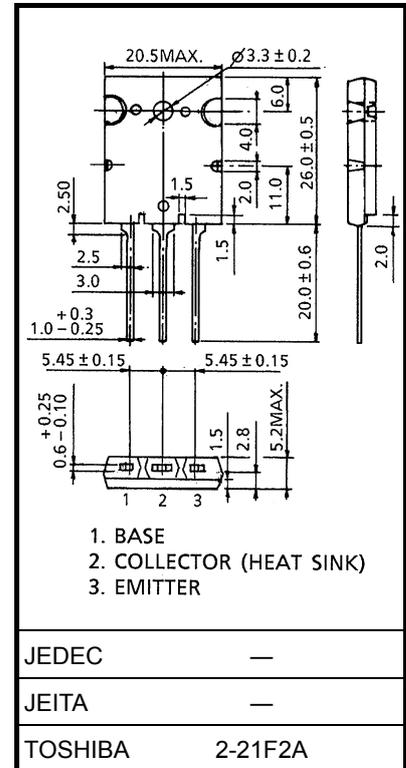
- High Voltage :  $V_{CBO} = 2000\text{ V}$
- Low Saturation Voltage :  $V_{CE(sat)} = 3\text{ V (Max.)}$
- High Speed :  $t_f = 0.15\mu\text{s (Typ.)}$

## ABSOLUTE MAXIMUM RATINGS ( $T_c = 25^\circ\text{C}$ )

| CHARACTERISTIC              |       | SYMBOL    | RATING  | UNIT             |
|-----------------------------|-------|-----------|---------|------------------|
| Collector-Base Voltage      |       | $V_{CBO}$ | 2000    | V                |
| Collector-Emitter Voltage   |       | $V_{CEO}$ | 900     | V                |
| Emitter-Base Voltage        |       | $V_{EBO}$ | 5       | V                |
| Collector Current           | DC    | $I_C$     | 22      | A                |
|                             | Pulse | $I_{CP}$  | 44      |                  |
| Base Current                |       | $I_B$     | 11      | A                |
| Collector Power Dissipation |       | $P_C$     | 220     | W                |
| Junction Temperature        |       | $T_j$     | 150     | $^\circ\text{C}$ |
| Storage Temperature Range   |       | $T_{stg}$ | -55~150 | $^\circ\text{C}$ |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

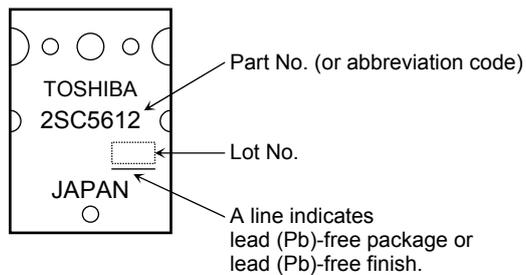


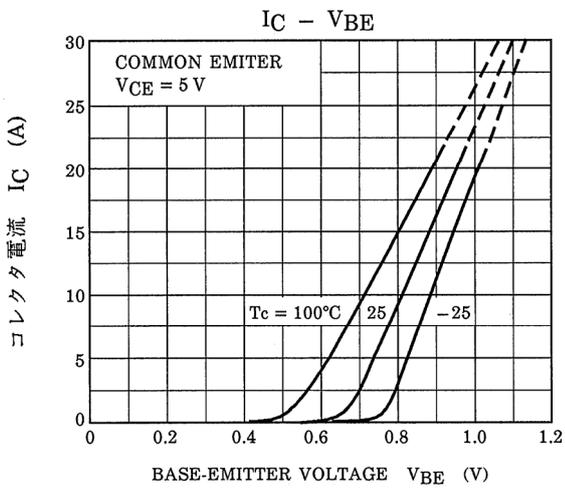
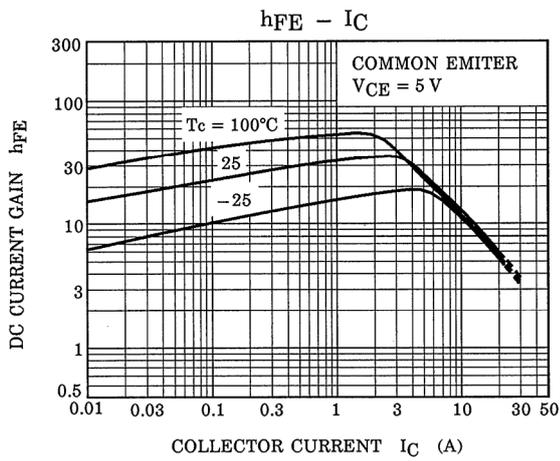
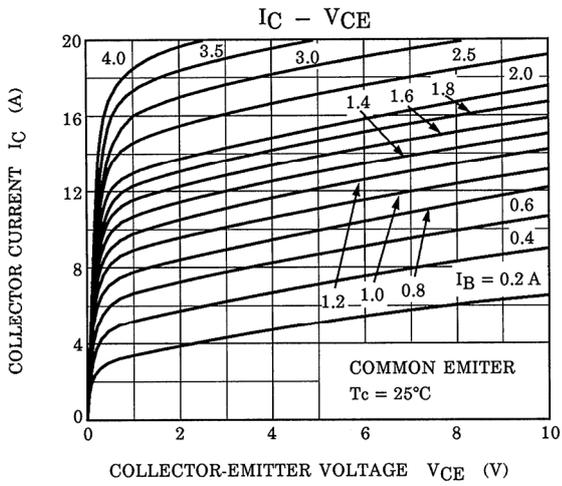
Weight: 9.75 g (typ.)

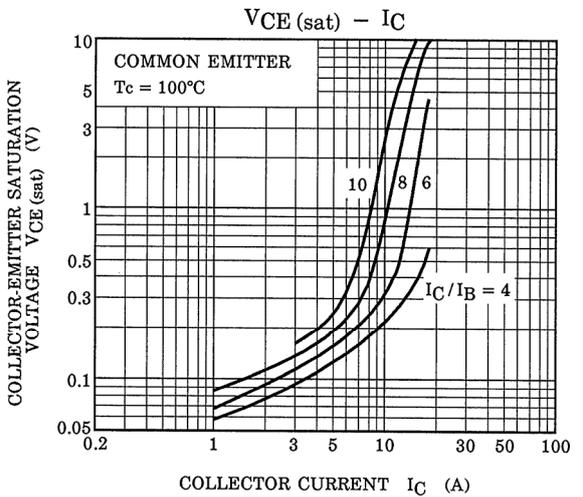
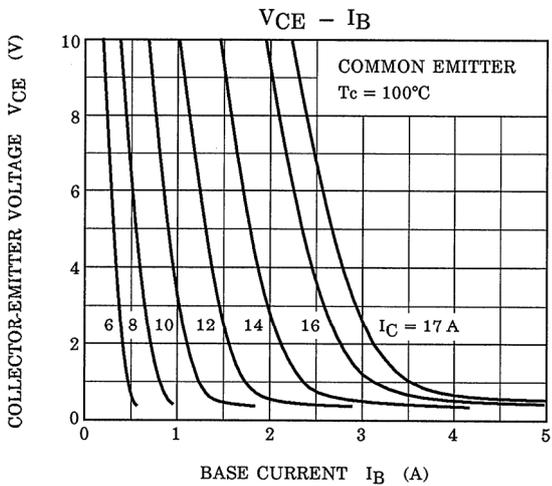
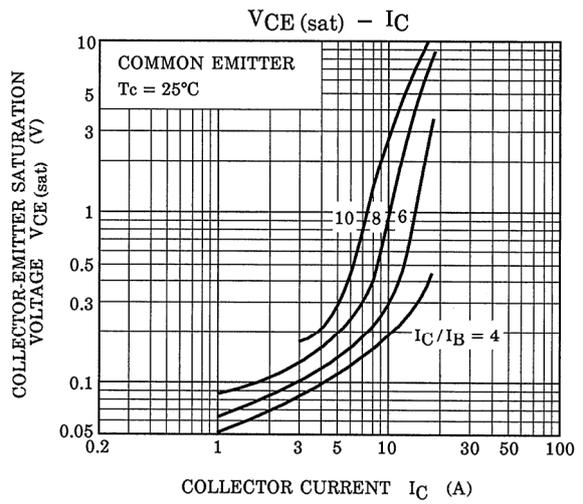
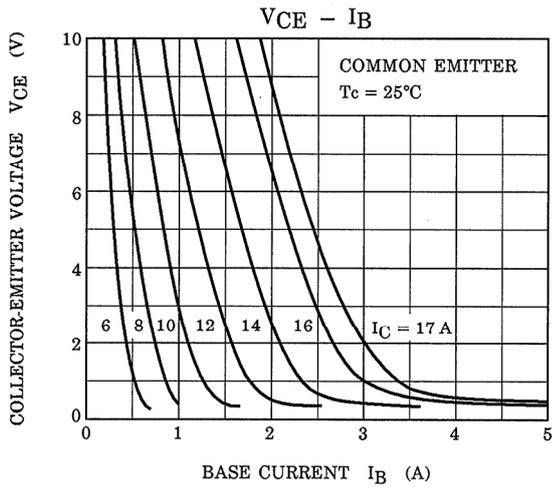
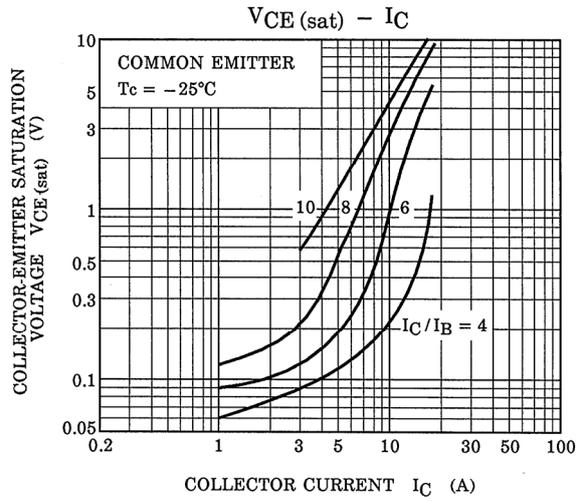
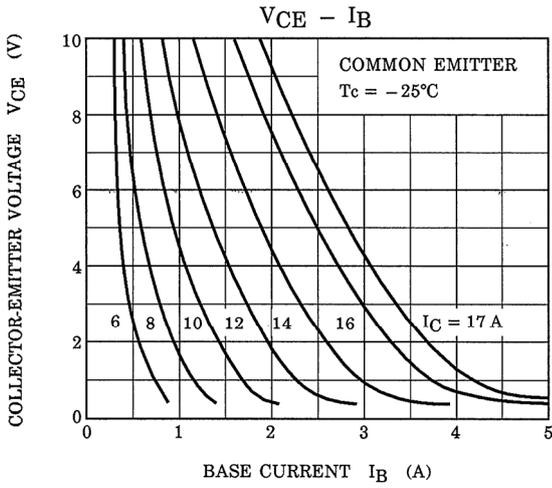
## ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25°C)

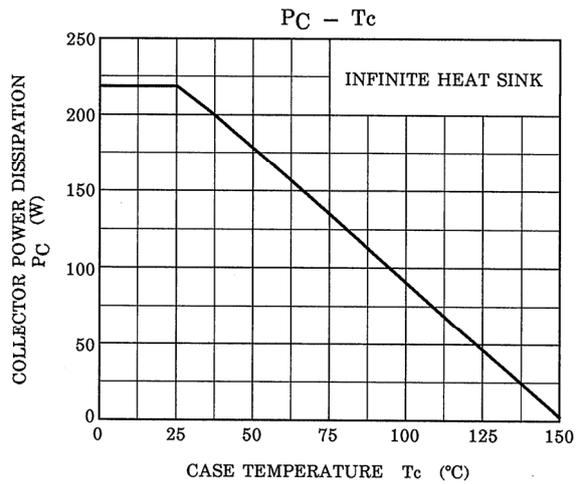
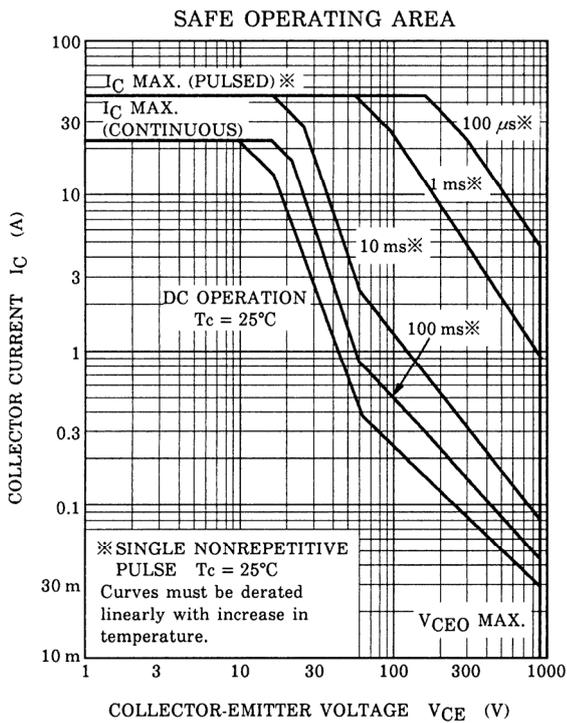
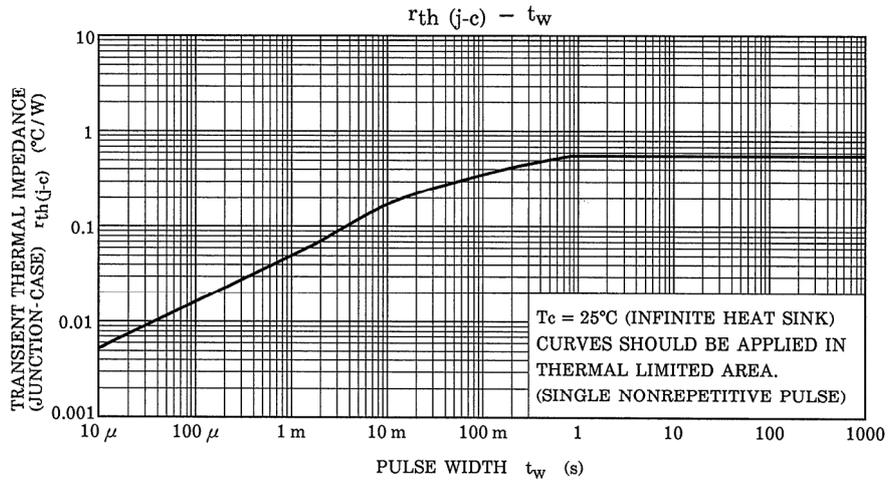
| CHARACTERISTIC                       |              | SYMBOL                | TEST CONDITION  | MIN | TYP. | MAX  | UNIT |
|--------------------------------------|--------------|-----------------------|---|-----|------|------|------|
| Collector Cut-off Current            |              | I <sub>CBO</sub>      | V <sub>CB</sub> = 2000 V, I <sub>E</sub> = 0                                  | —   | —    | 1    | mA   |
| Emitter Cut-off Current              |              | I <sub>EBO</sub>      | V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0                                     | —   | —    | 100  | μA   |
| Collector-Emitter Breakdown Voltage  |              | V (BR) CEO            | I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0                                    | 900 | —    | —    | V    |
| DC Current Gain                      |              | h <sub>FE</sub> (1)   | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 2 A                                   | 15  | —    | 50   | —    |
|                                      |              | h <sub>FE</sub> (2)   | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 9 A                                   | 9.5 | —    | 18.5 |      |
|                                      |              | h <sub>FE</sub> (3)   | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 17 A                                  | 4.8 | —    | 9.0  |      |
| Collector-Emitter Saturation Voltage |              | V <sub>CE</sub> (sat) | I <sub>C</sub> = 17 A, I <sub>B</sub> = 4.25 A                                | —   | —    | 3    | V    |
| Base-Emitter Saturation Voltage      |              | V <sub>BE</sub> (sat) | I <sub>C</sub> = 17 A, I <sub>B</sub> = 4.25 A                                | —   | —    | 1.3  | V    |
| Transition Frequency                 |              | f <sub>T</sub>        | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.1 A                                | —   | 2    | —    | MHz  |
| Collector Output Capacitance         |              | C <sub>ob</sub>       | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz                         | —   | 470  | —    | pF   |
| Switching Time                       | Storage Time | t <sub>stg</sub>      | I <sub>CP</sub> = 8 A, I <sub>B1</sub> (end) = 1 A<br>f <sub>H</sub> = 32 kHz | —   | 4.0  | 5.0  | μs   |
|                                      | Fall Time    | t <sub>f</sub>        |   | —   | 0.15 | 0.35 |      |

## MARKING









**RESTRICTIONS ON PRODUCT USE**

20070701-EN

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